New Jersey Semi-Conductor Products, Inc.

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1N5605 1N5606 1N5607 1N5608 1N5609 GENERAL PURPOSE DIODES

## GENERAL PURPOSE SILICON DIODES

This device is a Silicon Double Plug Diode for general purpose use in computer, industrial and military applications.



## ABSOLUTE MAXIMUM RATINGS

Storage temperature range,  $T_{itg}$ --65°C to +200°CLead or terminal temperature at a distance not less than+275°C1/16" from the seated surface (or case) for 15 seconds+275°C

	1N5605	1N5606	1N5607	1N5608/9
Reverse voltage, 25°C.free air	70 V	150 V	200 V	120 V
Maximum steady state power dissipation at 25°C, free air	250mw	200mw	200mw	250mw
Derating factor				2mw/°C

## ELECTRICAL CHARACTERISTICS

	1N5605		1N5606*		1N5607*	
	MIN	MAX	MIN	МАХ	MIN	MAX
Forward Voltage, VI @ If = 20 ma		1.0 V		1.0 V		1.0 V
Breakdown Voltage, Byr Ir = 100 ua	70 V		150 V		200 V	
Beverse Current Ir @ Vr = 60 V		25 na	T	25 na		25 па
Reverse Current, Ir @ Vr = 60 V @ 150°C		5 ua		5 ua		5 ua
			il = 7 ma.	Vr = 125 V	* if = 3 ma.	Vr = 175 V

## 1N5605 1N5606 1N5607 1N5608

ELECTRICAL CHARACTERISTICS - 1N5608	MIN	MAX
Forward Voitage, Vf @ If = 100 ma		1.0 V
Breakdown Voltage, Bvr		
Ir — 100 ua	120 V	
Reverse Current, Ir @ 50 V		50 na
Reverse Current, Ir @ 50 V @ 150°C		25 ua
*Reverse Recovery Time, Trr		
1f = 5 ma, Vr = 40 V		
R1 = 2 K, C1 = 10 pf		
Recover to 80K ohms		300 nsec

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NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

**Quality Semi-Conductors**